TEM estimated relative d-spacing (Si5218)
Bilayer
20
40
60
80
100
120
140
Relative d
1.0
1.1
1.2
1.3
Si5218_100k1B
Si5218_100k1T
Si5218_500k1B
Si5218_50k1B-1
Si5218_50k1B-2
Si5218_50k1B-3
Si5218_50k1B